ON Semiconductor®



Issue Date: 22 August 2017

Title of Change:	Improved SOT5X3 cross bar of carrier tape at ON Semiconductor, Leshan, China factory.		
Effective date:	22 August 2017		
Contact information:	Contact your local ON Semiconductor Sales Office or < <u>Coleen.Long@onsemi.com</u> >		
Type of notification:	ON Semiconductor will consider this change accepted.		
Change category:	ge category: 🛛 Wafer Fab Change 🗋 Assembly Change 🗍 Test Change 🛛 Other <u>Cross Bar of Carrier Tape Chang</u>		
Change Sub-Category(s): Manufacturing Site Change/Addition Manufacturing Process Change Product specific c		 Datasheet/Product Doc change Shipping/Packaging/Marking Other: 	
Sites Affected: ☐ All site(s) ☐ not applicable ☑ ON Semiconductor site(s) : ON Leshan, China			
Description and Purpose:			
Improved SOT5X3 cross bar of carrier tape to eliminate potential risk of unit rotate in tape. All new product releases currently incorporate this type of carrier tape and products listed in this product bulletin are being converted after the proposed ship date. The MPQ, reel size and cover tape dimension have no changes. There does not require any modifications to the assembly processes or flows. There is no change to the form, fit, or function of the physical part.			
List of Affected Standard Parts:			
NSV12100XV6T1G		NSVEMD4DXV6T5G	
NSVB143ZPDXV6T1G		NSVEMT1DXV6T1G	
NSVBA114EDXV6T1G		NSVEMT1DXV6T5G	
NSVBA114YDXV6T1G		NSVEMX1DXV6T1G	
NSVBAV70DXV6T5G		NSVR0320XV6T1G	
NSVBC114EDXV6T1G		NSVT30010MXV6T1G	
NSVBC114EPDXV6T1G		NSVT3904DXV6T1G	
NSVBC114YDXV6T1G		NSVT3906DXV6T1G	
NSVBC114YPDXV6T1G		NSVT3946DXV6T1G	
NSVBC123JPDXV6T1G		SBC847BPDXV6T1G	
NSVBC124EDXV6T1G		SBC847CDXV6T1G	
NSVBC124XPDXV6T1G		SNST3904DXV6T5G	
NSVBC143TPDXV6T1G		SZNUP4060AXV6T1G	
NSVBC143ZPDXV6T1G		SZNZQA5V6AXV5T1G	
NSVBC143ZPDXV6T5G		SZQA6V8XV5T1G	
NSVBC144EPDXV6T1G			
NSVEMC2DXV5T1G			